NSN 5962-01-123-7993



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-123-7993 **Body Length:** 0.440 inches **Body Width:** Between 0.240 inches and 0.325 inches **Body Height:** 0.085 inches **Maximum Power Dissipation Rating:** 910.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and programmable and bipolar and w/enable and 3-state output and w/buffered output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 45.00 nanoseconds propagation delay time, low to high level output and 89.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 82577-932820 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 flat leads Shelf Life:

Demilitarization: Voc. domil/mli

Unit Of Measure:

N/a

NSN 5962-01-123-7993

Memory Microcircuit - Page 2 of 2



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